

Product data sheet

1. General description

Enhanced ultrafast power diode in a SOD113 (2-lead TO-220F) plastic package.

2. Features and benefits

- High thermal cycling performance
- Isolated package
- Low thermal resistance
- Soft recovery characteristic
- Low on-state losses

3. Applications

- Dual Mode (DCM and CCM) PFC
- Power Factor Correction (PFC) for Interleaved Topology

4. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating	· · · · · ·					
V_{RRM}	repetitive peak reverse voltage			6	00		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _h ≤ 97 °C; Fig. 1; Fig. 2	5				A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _h ≤ 97 °C; square-wave pulse	10			A	
I _{FSM}	non-repetitive peak forward current	$t_{\rm p}$ = 10 ms; $T_{\rm j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	60 66			A	
		$t_{\rm p}$ = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse;			А		
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics	· · · · · ·				-	
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.3	1.9	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.1	1.7	V
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·					
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _i = 25 °C; <u>Fig. 6</u>		-	17.5	35	ns

5. Pinning information

Table	2.	Pinning	information
	_		monuton

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode		КА
mb	n.c.	mounting base; isolated	1 2 SOD113 (2-lead TO-220F)	001aaa020

6. Ordering information

Table 3. Ordering inform	nation		
Type number Package			
	Name	Description	Version
BYV25FX-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

7. Marking

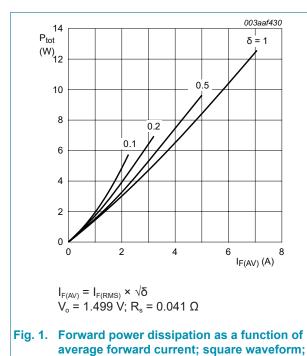
Table 4. Marking codes	
Type number	Marking codes
BYV25FX-600	BYV25FX-600

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V _{RWM}	crest working reverse voltage		600	V
V _R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _h ≤ 97 °C; Fig. 1; Fig. 2	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _h ≤ 97 °C; square-wave pulse	10	A
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	60	А
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	66	А
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C



maximum values

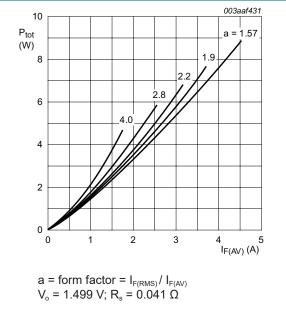
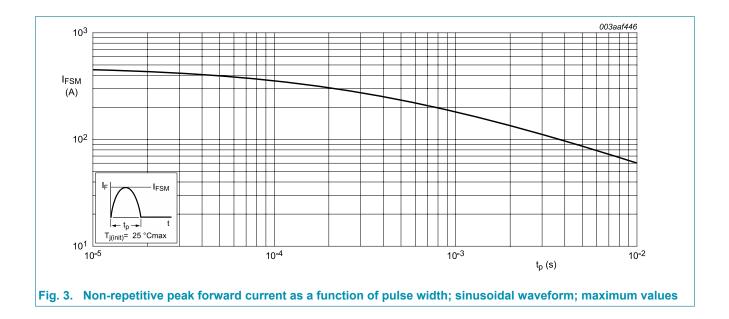
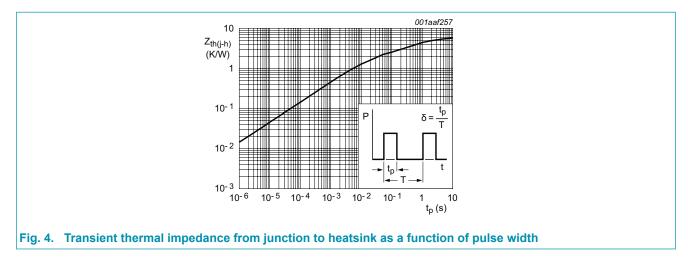


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-h)}}$	thermal resistance from junction to heatsink	with heatsink compound; Fig 4	-	-	5.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

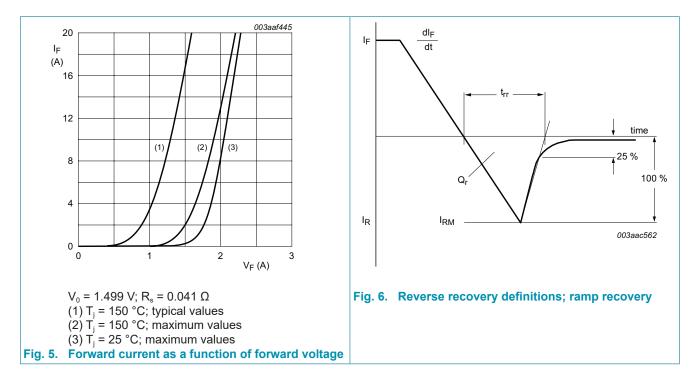


10. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	f = 1 MHz; from cathode to external heatsink	-	10	-	pF

11. Characteristics

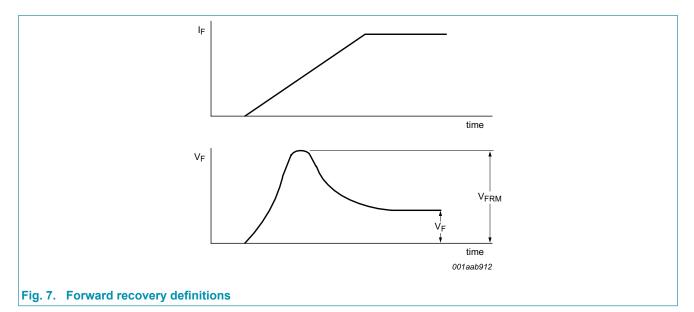
Table 8. Cl	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V_{F}	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.3	1.9	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 4</u>	-	1.1	1.7	V
I _R	reverse current	V _R = 600 V; T _j = 100 °C	-	-	1.5	mA
		V _R = 600 V; T _j = 25 °C	-	-	50	μA
Dynamic	characteristics					
Q _r	recovered charge	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 6</u>	-	13	-	nC
t _{rr}	reverse recovery time	$I_{F} = 1 \text{ A}; V_{R} = 30 \text{ V}; \text{ d}_{F}/\text{d}t = 100 \text{ A}/\mu\text{s}; T_{j} = 25 \text{ °C}; \frac{\text{Fig. 6}}{2}$	-	17.5	35	ns
I _{RM}	peak reverse recovery current	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	-	A
V_{FR}	forward recovery voltage	I _F = 1 A; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 6</u>	-	3.2	-	V



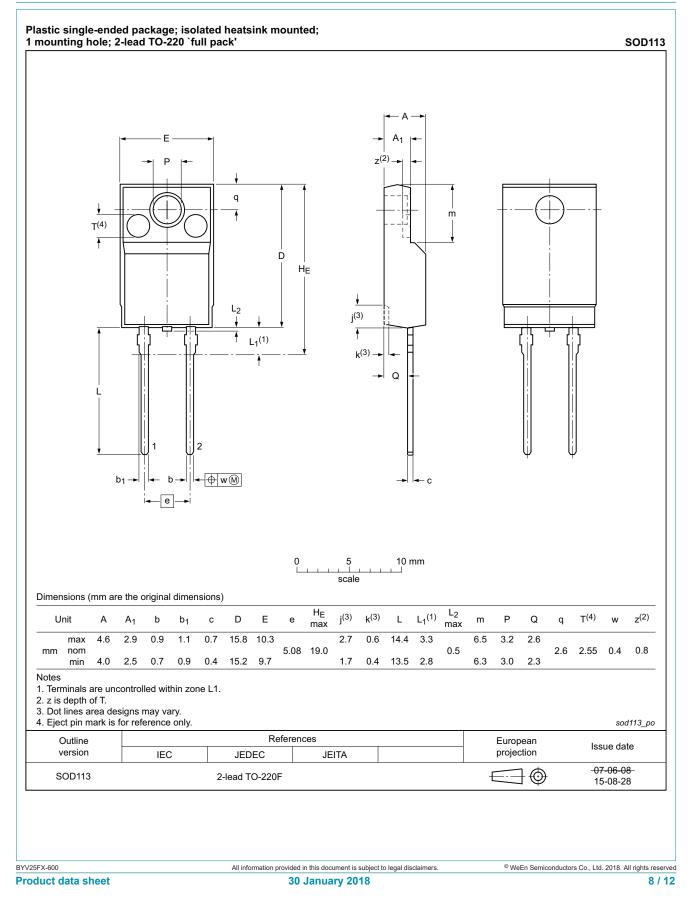
WeEn Semiconductors

BYV25FX-600

Enhanced ultrafast power diode



12. Package outline



13. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV25FX-600 v.3	20180130	Product data sheet	-	BYV25FX-600 v.2
Modifications:	Change from NXP version to WeEr	version		
BYV25FX-600 v.2	20110307	Product data sheet	-	BYV25FX-600 v.1
Modifications:	Various changes to content.	·		
BYV25FX-600 v.1	20101004	Product data sheet	-	-

BYV25FX-600

Enhanced ultrafast power diode

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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